



High Precision Protection Circuit for Li-ion or Li-polymer Battery

FEATURES

- Ideal protection circuit for one-cell Li-ion or Li-polymer battery
- High precision protection voltage threshold (over-charge/over-discharge)
- Allow or inhibit low power consumption mode
- High precision over-discharge protection current threshold
- Protection for battery short
- Multi-type of detector voltage and time delay option
- Allow or inhibit variable 0V battery charge
- Very few external elements
- Small SOT23-6 Package

APPLICATIONS

- Protection circuit for charge and discharge of Li-ion or Li-polymer battery
- High precision protector for cell phone battery and any other protector of Li-ion or Li-polymer battery

DESCRIPTION

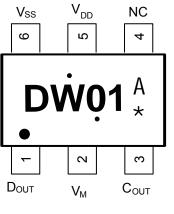
FHDW01C series are high precision protection ICs for over-charge and over-discharge of rechargeable one-cell Li-ion or Li-polymer battery. It integrates the high precision protection capability for over-charge, over-discharge, excess-current discharge, and battery short. Under normal conditions, when V_{DD} is between the protection thresholds of over-charge (V_{OC}) and over-discharge (V_{OD}), and the detection voltage of V_{M} is between the charger detect voltage (V_{CHG}) and excess-current discharge (V_{EDI}), the outputs of C_{OUT} and D_{OUT} are high conducting the N-MOSFET charge controller, Q1, and the N-MOSFET discharge controller, Q2. Thus, the battery can be charged through a charger and can be discharged through a load.

FHDW01C series realizes the over-charge and over-discharge protection through detecting the voltages of V_{DD} and V_{M} . When abnormal conditions occur during charging or discharging, the outputs of C_{OUT} and D_{OUT} both change from a high level to a low level, stopping charging or discharging by turning Q1/Q2 off.

All protections can be released at corresponding conditions. When the recovery condition is met, the outputs of C_{OUT}/D_{OUT} change from a low level to a high level, turning on Q1/Q2 to enable charge/discharge.

FHDW01C sets internal delay time for each protection and release. It does not enter into the protection or release state until its corresponding condition reaches its delay time. If the protection or release condition disappears in less than the corresponding delay time, it will not enter to either the protection or release state.

PIN CONFIGURATIONS



SOT23-6

Figure 1 FHDW01C Pin Configurations (Not to scale, *& • there are changes)

ORDERING INFORMATION

[Table 2] Detector Voltage Threshold and Delay Time

PARAMETER NAME	VALUE	ACCURACY RANGE
Protection threshold of over-charge V _{OCTYP}	4.300V	±25mV
Release threshold of over-charge $V_{\mbox{\scriptsize OCRTYP}}$	4.100V	±50mV
Protection threshold of over-discharge $V_{\mbox{\scriptsize ODTYP}}$	2.500V	±75mV
Release threshold of over-discharge V_{ODRTYP}	2.900V	±75mV
Protection threshold of excess-current discharge V_{EDITYP}	0.170V	±20mV
Protection delay time of over-charge $t_{\mbox{\scriptsize OCTYP}}$	110ms	±30%
Protection delay time of over-discharge $t_{\mbox{\scriptsize ODTYP}}$	55ms	±30%
Protection delay time of excess-current discharge $t_{\mbox{EDITYP}}$	7.0ms	±30%
0V-charge	Yes	
Low power consumption mode	Yes	

FUNCTIONAL DIAGRAM

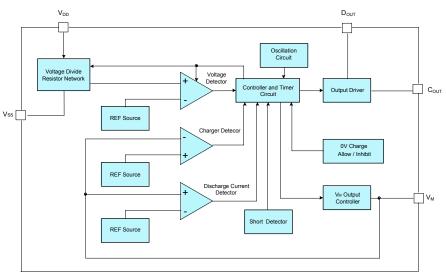


Figure 2 FHDW01C Functional Diagram

PIN DESCRIPTION

Table 3] PIN Description				
NAME	ORDER	I/O	FUNCTION	
D _{OUT}	1	0	Discharge Control Output Connect to the Gate of the external discharge controller N-MOSFET Q2.	
V _M	2	I	Charge/Discharge Current Sense Input Connect this to the Source of external charge controller N-MOSFET Q1 by a resistance (normally $1k\Omega$), then the voltage drop on Q1 and Q2, which cause by the charge/discharge current can be sensed.	
Соит	3	0	Charge Control Output Connect to the Gate of the external charge controller N-MOSFET Q1.	
NC	4		Not Connected	
V _{DD}	5	POW	Power Supply Input Connect to the positive of power supply (battery normally), a 0.1µF ceramic capacitor is required for decoupling.	
V _{SS}	6	POW	Ground Connect to the negative of power supply.	

ABSOLUTE MAXIMUM RATINGS

Power supply V_DD0.3V~+10V
$V_{\text{M}}, C_{\text{OUT}}$ acceptable voltage $V_{\text{DD}}\text{-}35V\text{-}V_{\text{DD}}\text{+}0.3V$
D_{OUT} acceptable voltage0.3V~V_{\text{DD}}+0.3V
Operation temperature T_A 40 $^\circ\!\mathrm{C}\text{-+85}^\circ\!\mathrm{C}$
Junction temperature150°C

Storage temperature65 $^\circ\!\!\!C\text{\sim}150^\circ\!\!\!C$
Power consumption P_D (T _A =25 °C)
SOT23-6 package (θ _{JA} =200°C/W)625mW
Solder Temperature (Tin soldering, 10s)



Note: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond the recommended operating condition are not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

ELECTRICAL SPECIFICATION

 $(V_{DD} = 3.6V, T_A = 25^{\circ}C, unless otherwise specified. The operation temperature with Mark "<math>\bullet$ " is: -40°C ≤ T_A≤85°C)

PARAMETER	SYMBOL	CONDITIOIN		MIN	TYP	MAX	UNI
Power supply	V _{DD}		•	1.5		10	V
Over-charge protection	M			V _{OCTYP} -0.025	VOCTYP	V _{OCTYP} +0.025	V
threshold (rising)	V _{oc}		•	V _{OCTYP} -0.080	V _{OCTYP}	V _{OCTYP} +0.080	V
Over-charge release Threshold(falling)	V _{OCR}	R1=100Ω (note)		V _{OCRTYP} -0.050	VOCRTYP	V _{OCRTYP} +0.050	V
			٠	V _{OCRTYP} -0.080	V _{OCRTYP}	V _{OCRTYP} +0.080	V
Over-charge protection delay time	t _{oc}	V _{DD} =3.6V→4.4V		0.7×t _{OCTYP}	t _{OCTYP}	1.3×t _{OCTYP}	ms
Over-discharge protection	N/			V _{ODTYP} -0.075	VODTYP	V _{ODTYP} +0.075	V
Threshold(falling)	V _{OD}		٠	V _{ODTYP} -0.105	V _{ODTYP}	V _{ODTYP} +0.105	V
Over-discharge release	M			V _{ODRTYP} -0.075	VODRTYP	V _{ODRTYP} +0.075	V
Threshold(rising)	V _{ODR}		٠	V _{ODRTYP} -0.105	VODRTYP	V _{ODRTYP} +0.105	V
Over-discharge protection delay time	t _{op}	V _{DD} =3.6V→2.4V		0.7×t _{ODTYP}	t _{odtyp}	1.3×t _{ODTYP}	ms
Excess-current discharge protection threshold	V_{EDI}			V _{EDITYP} -0.020	VEDITYP	V _{EDITYP} +0.020	V
Excess-current discharge protection delay time	t _{EDI}			0.7×t _{EDITYP}	T _{EDITYP}	1.3×t _{EDITYP}	ms
Excess-current discharge release delay time	t _{EDIR}			1.20	1.80	2.40	ms
Battery short protection threshold	V _{SHORT}	Voltage of V_{M}		0.82	1.36	1.75	V
Battery short protection delay time	t _{short}			200	400	600	μs
Charger detect voltage	V _{CHG}	V _{DD} =3.0V		-0.27	-0.5	-0.86	V
Resistance of V_M to V_{DD}	R_{VMD}	V _{DD} =1.8V, V _M =0V		100	300	900	kΩ
Resistance of V_M to V_{SS}	R _{VMS}			15	30	45	kΩ
C _{OUT} output low level pull-low resistor					4		MΩ
C_{OUT} output high level		V _{DD} =3.9V, I _{COUT} =10μA		V _{DD} -0.4	V _{DD} -0.2		V
D _{OUT} output low level		V _{DD} =2.0V, Ι _{DOUT} =10μΑ			0.2	0.4	V
D_{OUT} output high level		V _{DD} =3.9V, Ι _{DOUT} =10μΑ		V _{DD} -0.4	V _{DD} -0.2		V
Power current	I _{DD}	V _{DD} =3.9V			2.0	6.0	μA
Current under low power consumption mode	I _{PDWN}	V _{DD} =2.0V			0.7	1.0	μA
0V charge allow threshold (If 0V charge allow)	V_{0V_CHG}	Charger Voltage		1.2			V
0V charge inhibit threshold (If 0V charge inhibit)	V _{0V_INH}	Battery Voltage, V _M =-2.0V				1.2	V

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Note: 1. All the voltages are referred to $V_{\mbox{\scriptsize SS}}$, unless otherwise specified.

2. Shown in Figure 3.

FUNCTION DESCRIPTION

FHDW01C is a high precision protection circuit for the one-cell Li-ion or Li-polymer battery. Under normal conditions, during the battery charging, FHDW01Cmay get into the over-charge protection. It resets to the normal condition when it reaches the release condition. During the battery discharging, FHDW01C may get into the over-discharge or excess-current discharge protection. It can also reset to the normal state when it reaches the release condition. Figure 3 shows the typical application schematic. The state conversion diagram is shown in Figure 4. The detailed description of each condition is followed.

Normal Condition

Under normal conditions, FHDW01C is powered by the battery. When V_{DD} is between the protection thresholds of over-charge (V_{OC}) and over-discharge (V_{OD}), V_M is between the charger detect voltage (V_{CHG}) and excess-current discharge (V_{EDI}), the outputs of C_{OUT} and D_{OUT} become high and turn on the charge controller N-MOSFET Q1 and the discharge controller N-MOSFET Q2. Thus, the battery can be charged through a charger or discharged through a load.

Over-charge Protection

Protection condition

During the battery charging and under the normal condition, if the voltage of V_{DD} exceeds the over-charge protection threshold (V_{OC}) and this state lasts more than the over-charge protection delay time (t_{OC}), the voltage of C_{OUT} pin is equal to the voltage of V_M pin. The N-MOSFET's charge controller Q1 is turned off. The charge current is "shut off". FHDW01C gets into over-charge protection.

Release condition

FHDW01C can recover from over-charge protection when it meets one of the following two conditions. 1) The battery discharges itself to make V_{DD} lower than the over-charge release threshold (V_{OCR}); 2) The battery is discharged through an extra load (Note: Even though Q1 is turned off, discharge loop is still available due to its body diode), V_{DD} is lower than the over-charge protection threshold (V_{OC}), and the voltage of V_M pin is higher than the excess-current discharge protection threshold (V_{EDI}). (Before Q1 is turned on, the voltage of V_M is one diode voltage higher than the voltage of V_{SS}).

After FHDW01C recovers to normal condition, the output of C_{OUT} pin goes to a high level. The charge controllerN-MOSFET, Q1, is turned on again.

Once FHDW01C enter into over-charge protection, it will never release to normal condition if a charger isalways connected, even if its V_{DD} is below V_{ODR} . It only can be released by disconnecting the charger.

Over-discharge Protection/Low Power Consumption Mode

Protection condition

Under normal conditions, if the voltage of $V_{\text{DD}}\,\text{pin}$ is

lower than the over-discharge protection threshold (V_{OD}) and this state lasts more than the over-discharge protection delay time (t_{OD}) , the voltage of D_{OUT} pin goes to low(V_{SS}) from a high level. The discharge controller N-MOSFET, Q2, is turned off, shutting off the discharging loop. FHDW01C gets into the over-discharge protection. The voltage of V_M pin is pulled up to V_{DD} through the internal resistor, R_{VMD}.

During over-charge protection, the voltage of V_M pin (equal to V_{DD}) is always higher than the battery short protection threshold (V_{SHORT}). Thus, the circuit gets into a low power consumption or "Power saving" mode. In this mode, the current of V_{DD} pin is less than 0.7 μ A.

Release condition

In the low power consumption mode, the battery should be charged to make the voltage of V_M pin lower than the battery short protection threshold (V_{SHORT}), and then FHDW01C can recover to the over-voltage discharge protection.(The charging circuit is still available due to the diode in Q2). Under this condition, the output level of D_{OUT} is held low, and Q_2 is still turned off. If stopped from charging, FHDW01C returns to the low power consumption mode, because thevoltage of V_M pin is still pulled up to V_{DD} by the R_{VMD} resistor and the voltage is higher than the battery shortprotection threshold (V_{SHORT}). Only when the battery ischarged continually until the voltage of V_{DD} pin risesabove the over-discharge protection threshold (V_{OD}),FHDW01C can recover to the normal condition from theover-discharge protection.

FHDW01C also can release to the normal conditionfrom the over-discharge protection, if the battery's self-voltage lifting feature makes the voltage of V_{DD} higher than the over-discharge release threshold (V_{ODR}). After FHDW01C recovers to the normal condition, theoutput of D_{OUT} pin goes to a high level. The charge controller N-MOSFET, Q2, is turned on again.

Excess-current Discharge/Battery Short Protection

Protection condition

FHDW01C supplies two-step excess-current protection.

Under normal conditions, during the battery discharging through a load, the voltage of V_M pin rises with the discharge current increasing. If the discharge current increases to make the voltage of V_M pin exceed the excess-current discharge protection threshold (V_{EDI}) for more than the excess-current discharge protection delay time (t_{EDI}), FHDW01Cgets into the excess-current discharge protection. If thedischarge current increases continuously to make thevoltage of V_M pin exceed the protection battery shortthreshold (V_{SHORT}), FHDW01C gets into the battery short protection.

When FHDW01C is in the excess-current discharge protection or battery short protection, the output of D_{OUT} pin changes from a high level to a low level (V_{SS}).

The external discharge controller N-MOSFET Q2 is turned off, shutting off the discharge loop. V_M is connected to the V_{SS} through the internal resistor R_{VMS}. Once the discharge load is removed, the level of V_M pin changes to the level of V_{SS} pin.

Release condition

In the excess-current discharge protection or the battery short protection, when the voltage of V_M pin drops lower than the excess-current discharge protection threshold V_{EDI} for more than the excess-current discharge release delay time (t_{EDIR}), FHDW01C recovers to the normal condition.

FHDW01C self-releases under the excess-current dischargeprotection or the battery short protection whenremoving all of the discharge loads.

After FHDW01C recovers to the normal condition, the output of D_{OUT} pin goes to a high level. The charge controller N-MOSFET, Q2, is turned on again.

Charger Detection

When a battery in the over-discharge condition is connected to a charger and provided that the V_M pin voltage is lower than the charger detect voltage (V_{CHG}), the FHDW01C releases the over-discharge condition and turns the discharge controller N-MOSFET, Q1 onwhen the battery voltage becomes equal to or higherthan the over-discharge threshold voltage (V_{OD}) sincethe charger detect function works. This action is calledcharger detection.

When a battery in the over-discharge condition is connected to a charger and provided that the V_M pin voltage is not lower than the charger detect voltage (V_{CHG}), the FHDW01C releases the over-discharge condition when the battery voltage reaches the over-discharge release threshold voltage (V_{ODR}).

OV Battery Charging

• 0V battery charge

This function is used to recharge the battery whose voltage is 0V due to self-discharging. If the battery is charged until V_{DD} is higher than V_M about 0V charge threshold (V_{0V_CHG}), the C_{OUT} pin is connected to the V_{DD} . If the voltage of the C_{OUT} pin is high enough to turn on the charge controller N-MOS, Q1, a charging circuit is formed through the diode built in the discharge controller N-MOS, Q2. The battery voltage rises. When V_{DD} is higher than over-voltage discharge protection threshold (V_{OD}), FHDW01C enters the normal condition. The output of discharge control pin (D_{OUT}) is high. The discharge controller N-MOS is turned on.

0V battery charge inhibition

If 0V battery charge is inhibited, the charge control pin (C_{OUT}) is connected to the V_M pin, when V_{DD} is lower than the 0V charge inhibition threshold (V_{NOCHG}). The charge controller N-MOS is turned off.

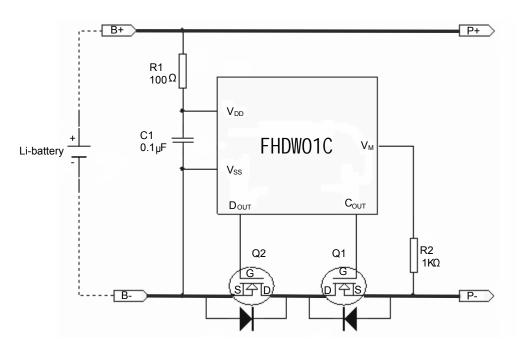


Figure 3 FHDW01C Typical Application Schematic

STATE CONVERSION DIAGRAM

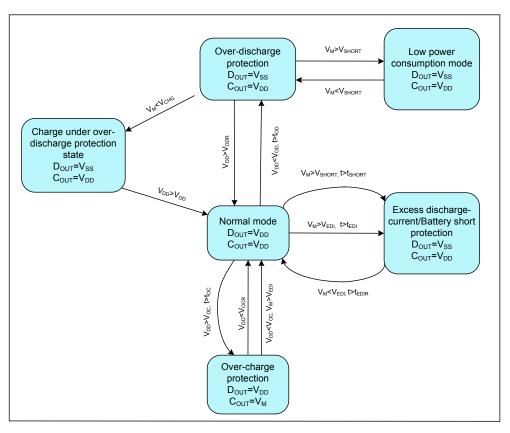


Figure 4 FHDW01C State Conversion Diagram

STATE CONVERSION AND TIMING DIAGRAM

Over-charge/Over-discharge Protection

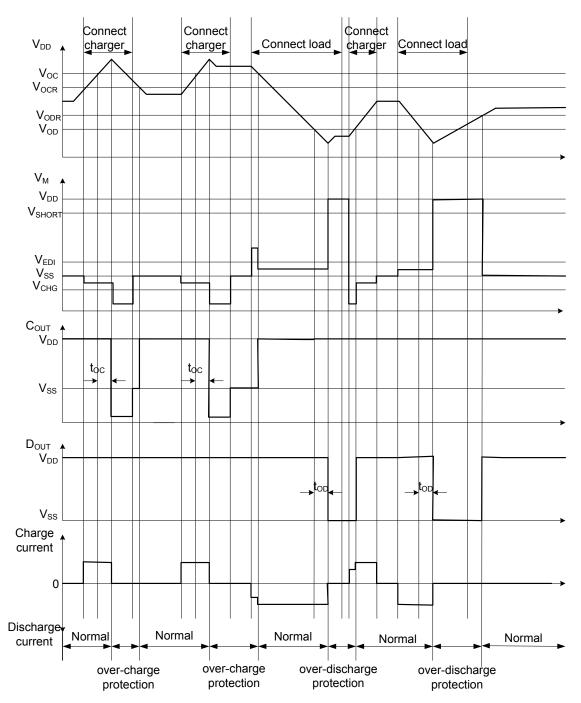


Figure 5 Timing Diagram of Over-charge/Over-discharge Protection

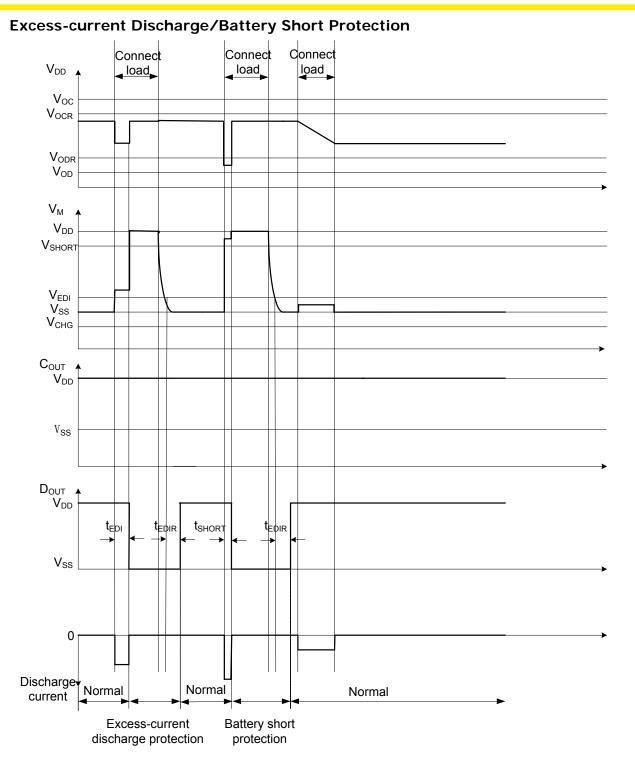


Figure 6 Timing Diagram of Excess-current Discharge/Battery Short Protection

APPLICATION NOTES

Selection of Q1 and Q2

Same type of N-MOSFET can be chosen for Q1 and Q2. The threshold voltage, V_{th} should be between 0.4V and the over-discharge protection threshold voltage (V_{OD}). If V_{th} is less than 0.4V, Q1 might not be turned off. If V_{th} is higher than V_{OD}, Q2 might be turned off before the over-discharge is detected.

The breakdown voltages between the gate and the source (BV_{GS}) of Q1 and Q2 should be higher than the charger voltage, V_{DD} . Otherwise, Q1 and Q2 can be destroyed during charging.

Selection of R1 and R2

The recommended values of R1 and R2 are 100Ω and $1K\Omega$, respectively. Here R1 should be smaller than R2.

In this application, all the detection thresholds are referred to as V_{DD} . The V_{DD} is connected to the battery through a resistor, R1.The difference between each

PACKAGE DIMENSION : SOT23-6

threshold and the battery voltage increases with the increase of R1. If the charger is connected reversely, the voltage of V_{DD} pin and V_{SS} pin may exceed the maximum rating. The IC could be destroyed. Therefore, the value of R1 should be chosen within $500\Omega.$

If the value of R2 is too small, the current of the IC may be higher than the maximum rating. The IC could be destroyed if the charge is connected reversely. If the value of R2 is too large and a high-voltage charger is connected, the charging current may not be shut off. So the proper value of R2 should be between 500 Ω and 2.2K Ω .

Selection of C1

A filter network is composed of C1 and R1, which filters the power supply. A 0.1μ F~1uF ceramic capacitor canbe chosen for C1.

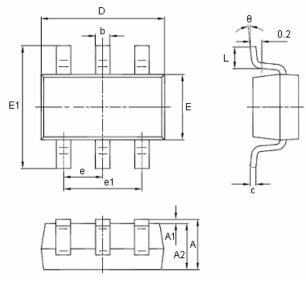


Figure 7 SOT23-6 Package

SYMBOL	MIN	MAX			
А	1.050	1.250			
A1	0.000	0.100			
A2	1.050	1.150			
b	0.300	0.500			
с	0.100	0.200			
D	2.280	3.020			
E	1.500	1.700			
E1	2.650	2.950			
е	0.950 (BSC)				
e1	1.800	2.000			
L	0.300	0.600			
θ	0°	8°			
a.					

[Table 5] Physical Dimensions in figure 9 (Unit:mm)